HD74LS373 Octal D-type Transparent Latches (with three-state outputs) outputs)

The HD74LS373, 8-bit register features totem-pole three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. The high-impedance third state and increased high-logic-level drive provide this register with the capacity of being connected directly to and driving the bus lines in a bus-organized system without need for interface or pull-up components. They are particularly attractive for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight latches are transparent D-type latches meaning that while the enable (G) is high the Q outputs will follow the data (D) inputs. When the enable is taken low the output will be latched at the level of the data that was setup.

EFUNCTION TABLE

	Output		
Output control	Enable G	D	Q
L	н	Н	H
L	Н	L.	L
L	L	×	Q ₀
Н	×	×	Z

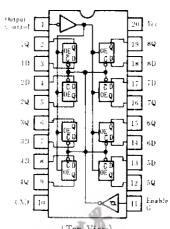
Notes:

H = high level, L = low level, X = irrelevant

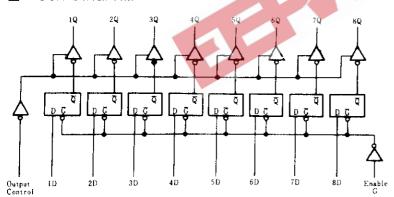
level of Q before the indicated steady-state input conditions were established.

off (high-impedance) state of a three-state output

MPIN ARRANGEMENT



■BLOCK DIAGRAM



MRECOMMENDED OPERATING CONDITIONS

Item		Symbol	min	typ	max	Unit
Supply voltage Output voltage		Vcc	4.75	5.00	5.25	V
		V _{OH}	-		5.5	v
Output current		Іон		_	-2.6	mА
		Ioi			24	mA
Enable pulse	"H" level	f w	15		_	
width	"L" level		15			ns
Data setup time		t zu	5↓	-		ns
Data hold time		ts	25 ↓	_		ns

Note) 4 : The arrow indicates the falling edge of clock pulse.

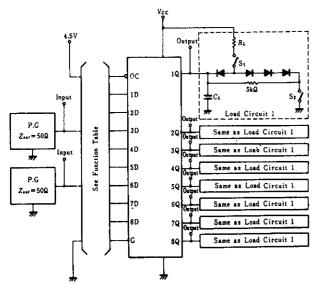
ELECTRICAL CHARACTERISTICS $(Ta = -20 \sim +75^{\circ}C)$

Item	Symbol	Test Conditions		min	typ*	max	Unit
	VIH			2.0	_		V
Input voltage		Data inputs			0.7	v	
	VIL	G. Output control inputs		_		0.8	V
	Von	$V_{CC} = 4.75 \text{V}, \ V_{IH} = 2 \text{V}, \ V_{IL} = V_{I}$	L max, I _{OH} = -2.6mA	2.4	_	_	v
Output voltage		$V_{cc}=4.75$ V. $V_{tH}=2$ V.	IoL - 12mA	_		0.4	v
	Vol		IoL - 24mA			0.5	
	Іогн		Vo-2.7V	_	_	20	
Off-state output current	Iozz	$V_{cc} = 5.25 \text{V}, V_{tH} = 2 \text{V}$	Vo-0.4V	_	_	20	μΑ
	ItH	$V_{cc} = 5.25 \text{V}, V_t = 2.7 \text{V}$				20	μA
Input current	IIL	Vcc-5.25V, Vt-0.4V			-0.4	mA	
II		$V_{cc} = 5.25 \text{V}, V_{l} = 7 \text{V}$	_		0.1	mA	
Short-circuit output current	Ios	Vcc-5.25V	-30	_	-130	mA	
Supply current	Icc	Vcc-5.25V, Vi-4.5V (Output control)			24 📣	40	mA
Input clamp voltage	VIK	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$			一点几	-1.5	V

Supply current	lcc	Vcc= 5.25	$V_1 = 4.3$	V (Output control)		54		11111
Input clamp voltage	V_{IK}	$V_{cc} = 4.75$	V, I _{IN} =-	18mA		. <i>j</i> . j.	-1.5	V
V _{CC} =5V, Ta=25°C					为海		100	
					12 79	C		
				186		400		
SWITCHING CHAR	ACTERIS	TICS (V	$r_{cc}=5V$.	$Ta = 25^{\circ}C$	_0			
		- 			min	A	max	Unit
Item	Symbol	Input	Output	Test Conditions	min	typ		Onte
	t plH	D	Q			12	18	
	tpHL	D D	W		-	12	18	
Propagation delay time	t _{PLH}			$C_L = 45 pF$	_	20	30	
	t _{PHL}	G	Q	$R_L = 667\Omega$	_	18	30]
	t _{zH}				_	15	28	ns
Output enable time	tzL	OC	Q			25	36	1
				C _L -5pF		12	20	1
Output disable time $\frac{t_{HZ}}{t_{LZ}}$	OC	Q				25	l	
	tuz		1	$R_L = 667\Omega$		15	25	

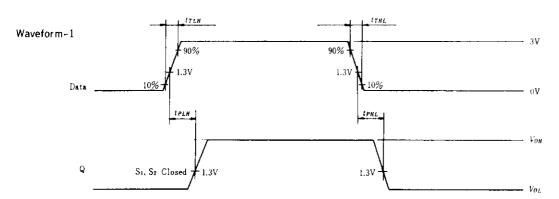
TESTING METHOD

Test Circuit

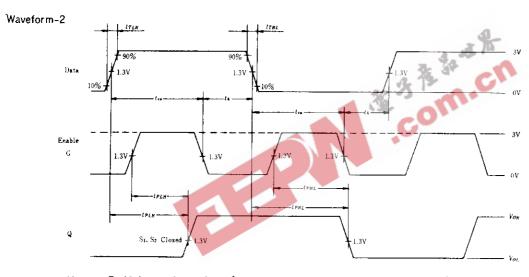


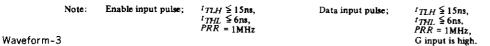
 C_L includes probe jig capacitance.
 All diodes are 1S2074 (H). Notes:

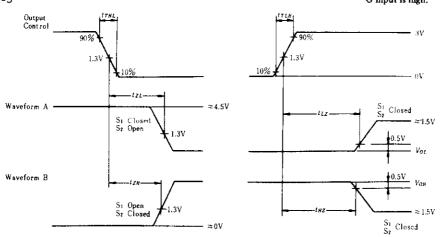
HD74LS373



Notes: Input pulse; $t_{TLH} \le 15$ ns, $t_{THL} \le 6$ ns, PRR = 1MHz, duty cycle 50%





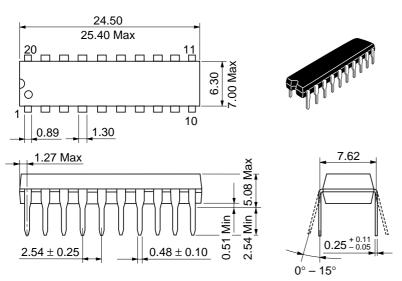


Notes:

 Input pulse; t_{TLH} ≤ 15ns, t_{THL} ≤ 6ns, PRR = 1MHz, duty cycle 50%
 Waveform A if for an output with internal conditions such that the output is low except when disabled by the output control. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.



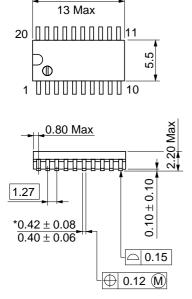
Unit: mm



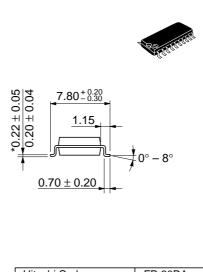
Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g







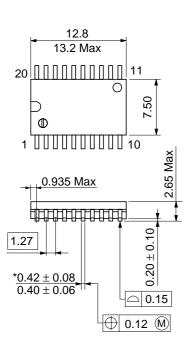
12.6



Hitachi Code	FP-20DA
JEDEC	_
EIAJ	Conforms
Weight (reference value)	0.31 g

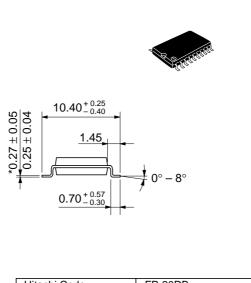
*Dimension including the plating thickness
Base material dimension





*Dimension including the plating thickness

Base material dimension



Unit: mm

Hitachi Code FP-20DB

JEDEC Conforms

EIAJ —

Weight (reference value) 0.52 g

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